

View Online at <https://aerobasegroup.com/nsn/5961-01-206-4137>

Inclosure Material:

Ceramic all semiconductor device diode and metal all semiconductor device diode

Overall Length:

1.000 inches all semiconductor device diode

Overall Diameter:

0.620 inches all semiconductor device diode

Mounting Facility Quantity:

1 all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

2 semiconductor device diode

Mounting Method:

Threaded stud all semiconductor device diode

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

1.0 forward voltage, dc all semiconductor device diode

Capacitance Rating In Picofarads:

0.23 all semiconductor device diode and 0.27 all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius ambient air all semiconductor device diode

Test Data Document:

53711-6116243 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

1 case all semiconductor device diode and 1 threaded stud all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

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